

IIT-I secures another patent

INDORE: Indian Institute of Technology Indore has secured another patent, this time for an invention by two of its faculty members. The patent has been granted for invention titled "An Ultra Low Power, Read Decoupled-Differential Write, 10T SRAM Cell with Higher Read/Write Noise Margin" for a period of 20 years. The inventors are Vishal Sharma and Santosh Kumar Vishvakarma. This is second patent secured by the elite institute which came into being in 2009.